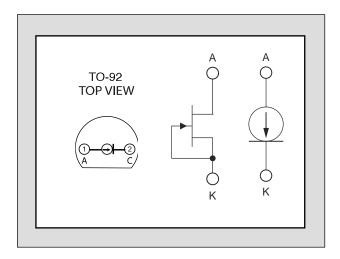


Improved Standard Products®

FEATURES						
REPLACES SILICONIX/VISHAY J500 SERIES						
WIDE CURRENT RANGE	0.192 to 5.6mA					
BIASING NOT REQUIRED	$V_{GS} = 0V$					
ABSOLUTE MAXIMUM RATINGS ¹						
@ 25 °C (unless otherwise stated)						
Maximum Temperatures						
Storage Temperature	-55 to 150°C					
Junction Operating Temperature	-55 to 150°C					
Maximum Power Dissipation						
Continuous Power Dissipation @25°C	350mW					
Maximum Currents						
Forward Current	20mA					
Reverse Current	50mA					
Maximum Voltages						
Peak Operating Voltage	Pov = 50V					

J500 SERIES

CURRENT REGULATING DIODES



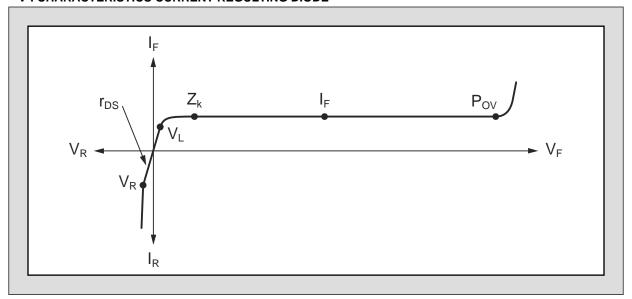
COMMON ELECTRICAL CHARACTERISTICS @ 25 °C (unless otherwise stated)

SYMBOL	CHARACTERISTIC	MIN	TYP	MAX	UNITS	CONDITIONS
Pov	Peak Operating Voltage ⁶	50			V	$I_F = 1.1I_{F(max)}$
V_R	Reverse Voltage		0.8		V	$I_R = 1mA$
CF	Forward Capacitance		2.2		pF	$V_F = 25V, f = 1MHz$

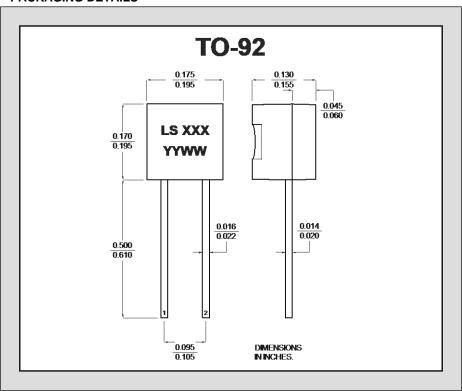
SPECIFIC ELECTRICAL CHARACTERISTICS @ 25 °C (unless otherwise stated)

PART	Forward Current ³ I _{F(mA)}			_	mpedance ⁴ _{ΜΩ)}	Knee Impedance Z _{k(MΩ)}	Limiting Voltage ⁵	
	V _F = 25V			V _F = 25V		V _F = 6V	I _F = 0.8I _{F(min)}	
	MIN	NOM	MAX	MIN	TYP	TYP	TYP	MAX
J500	0.192	0.24	0.288	4.00	15	2.50	0.4	1.2
J501	0.264	0.33	0.396	2.20	10	1.60	0.5	1.3
J502	0.344	0.43	0.516	1.50	7	1.10	0.6	1.5
J503	0.448	0.56	0.672	1.20	5	0.80	0.7	1.7
J504	0.600	0.75	0.900	0.80	3.5	0.55	0.8	1.9
J505	0.800	1.00	1.200	0.50	2.	0.40	0.9	2.1
J506	1.120	1.40	1.680	0.33	1.5	0.25	1.1	2.5
J507	1.440	1.80	2.160	0.20	1	0.19	1.3	2.8
J508	1.900	2.40	2.900	0.20	0.7	0.13	1.5	3.1
J509	2.400	3.00	3.600	0.15	0.5	0.09	1.7	3.5
J510	2.900	3.60	4.300	0.15	0.4	0.07	1.9	3.9
J511	3.800	4.70	5.600	0.12	0.3	0.05	2.1	4.2

V-I CHARACTERISTICS CURRENT REGULTING DIODE



PACKAGING DETAILS



Notes

- Absolute maximum ratings are limiting values above which serviceability may be impaired.
- Pulsed, t = 2ms. Steady state currents may vary.
 Pulsed, t = 2ms. Continuous currents may vary.
- 3.
- Pulsed, t = 2ms. Continuous impedances may vary.
- Min V_F required to ensure $I_F = 0.8I_{F(min)}$.

 Max V_F where I_F = 1.1x_{F(max)}, is guaranteed. Pulsed test ≤2_{ms}.
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